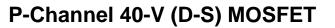
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Top View

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PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)			
- 40	0.0071 at V_{GS} = - 10 V	- 60	97 nC			
	0.0098 at V _{GS} = - 4.5 V	- 40	37 NC			

FEATURES

- **DT-Trench Power MOSFET**
- 100 % R_g and UIS Tested

APPLICATIONS

 Notebook - Load Switch

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ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise not	ed	
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	- 40	V
Gate-Source Voltage		V _{GS}	± 20	v
	T _C = 25 °C		- 60 ^a	
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 70 °C	I _D	- 50 ^a	
	T _A = 25 °C	·U	- 15 ^{b, c}	
	T _A = 70 °C		- 8 ^{b, c}	А
Pulsed Drain Current $T_c = 25 ^{\circ}C$		I _{DM}	- 240	7
Continuous Source-Drain Diode Current	Diode Current $T_{\rm C} = 25 ^{\circ}{\rm C}$ $-60^{\rm a}$			
	T _A = 25 °C	-3	- 15 ^{b, c}	
Single Pulse Avalanche Current L = 0.1 mH		I _{AS}	- 58	
Single Pulse Avalanche Energy		E _{AS}	187	mJ
	T _C = 25 °C		97	
Maximum Power Dissipation	T _C = 70 °C	P _D	63	w
	T _A = 25 °C	. D	5.15 ^{b, c}	
	T _A = 70 °C		3.2 ^{b, c}	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C
Caldering Decomposed at an a (Deck Terrane return)		260	U	

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^{b, f}	t ≤ 10 s	R _{thJA}	20	40	°C/W		
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	0.9	1.5	0/11		

Notes:

a. Package limited.

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. The DFN5x6 is a leadless package. The end of the lead terminal is exposed

copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

f. Maximum under Steady State conditions is 54 °C/W.

Soldering Recommendations (Peak Temperature)^{d, e}

DFN5X6 Top View Bottom View

- PIN1





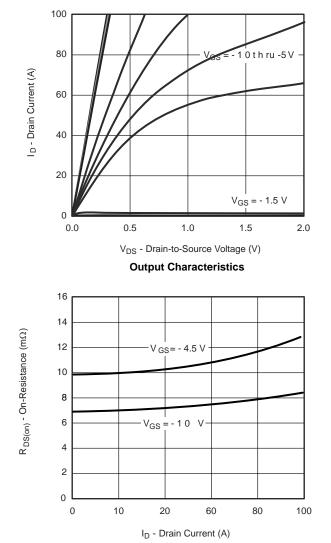
RoHS COMPLIANT

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = -250 \mu A$	- 40			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = - 250 μA		- 35		mV/°C
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	i _D = - 250 μA		6.5		
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0		- 3.0	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zara Cata Valtaga Drain Current	1	$V_{DS} = -32 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μA
Zero Gate Voltage Drain Current	IDSS	V_{DS} = - 32 V, V_{GS} = 0 V, T_{J} = 55 °C			- 10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 60			А
		V _{GS} = - 10 V, I _D = - 20 A		0.0071	0.0085	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 15 A		0.0098	0.013	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 20 A		16		S
Dynamic ^b						
Input Capacitance	C _{iss}			7750		
Output Capacitance	C _{oss}	V_{DS} = - 32 V, V_{GS} = 0 V, f = 1 MHz		1089		pF
Reverse Transfer Capacitance	C _{rss}			302		
Total Gate Charge	Qg	$V_{DS} = -32$ V, $V_{GS} = -10$ V, $I_{D} = -20$ A		97	150	nC
				75	130	
Gate-Source Charge	Q _{gs}	$V_{\rm DS}$ = - 32 V, $V_{\rm GS}$ = - 4.5 V, $I_{\rm D}$ = - 15 A		11		
Gate-Drain Charge	Q _{gd}			33		
Gate Resistance	Rg	f = 1 MHz		2.0		Ω
Turn-On Delay Time	t _{d(on)}			45		
Rise Time	t _r	V_{DD} = - 32 V, R _L = 15 Ω		19		
Turn-Off Delay Time	t _{d(off)}	$\rm I_D \cong$ - 20 A, $\rm V_{GEN}$ = - 10 V, $\rm R_g$ = 1 Ω		130		
Fall Time	t _f			77		
Turn-On Delay Time	t _{d(on)}			55		ns
Rise Time	t _r	V_{DD} = - 32 V, R _L = 15 Ω		27		-
Turn-Off Delay Time	t _{d(off)}	$\rm I_D \cong$ - 15 A, $\rm V_{GEN}$ = - 4.5 V, $\rm R_g$ = 1 Ω		217		
Fall Time	t _f			85		
Drain-Source Body Diode Characteristi	cs					
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C			- 60	A
Pulse Diode Forward Current ^a	I _{SM}				- 240	
Body Diode Voltage	V _{SD}	I _S = - 5 A		- 0.6	- 1.2	V
Body Diode Reverse Recovery Time	t _{rr}			50	120	ns
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = 20 A, dI/dt = 100 A/μs, T _J = 25 °C		65	136	nC
Reverse Recovery Fall Time	t _a	$r_F = 20 \text{ A}, \text{ and } r = 100 \text{ A/} \mu \text{s}, r_J = 20 \text{ C}$		26		
Reverse Recovery Rise Time	t _b	1		24		ns

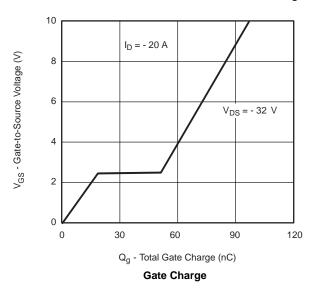
Notes:

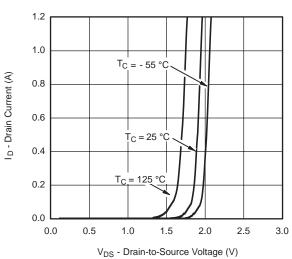
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

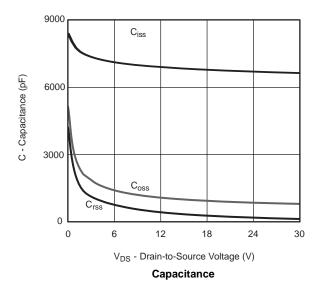


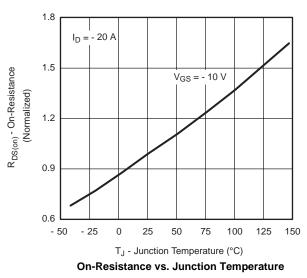
On-Resistance vs. Drain Current and Gate Voltage



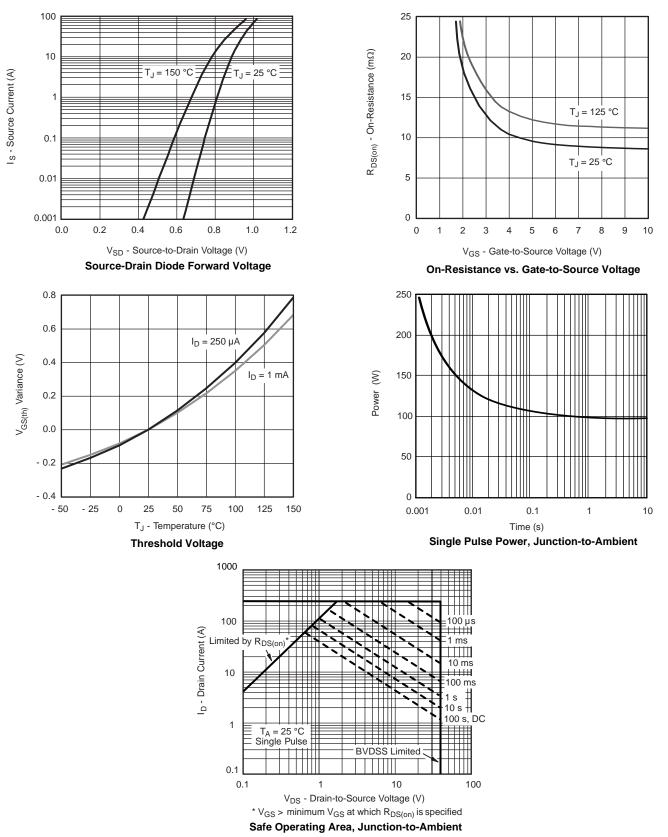


Transfer Characteristics

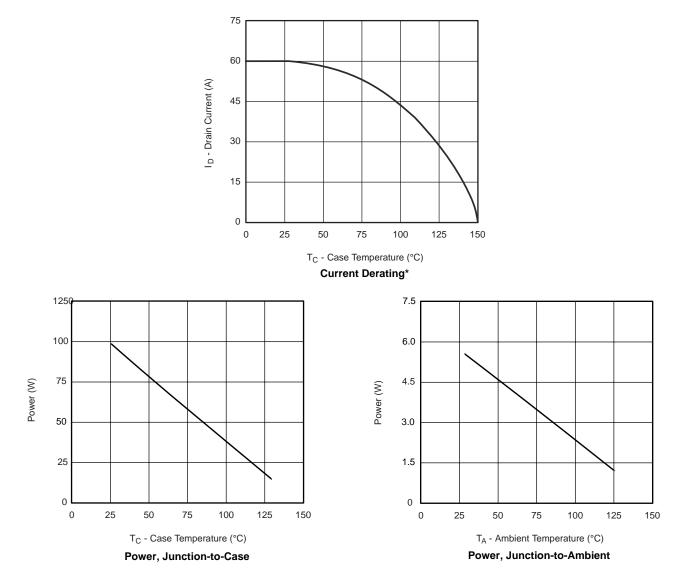




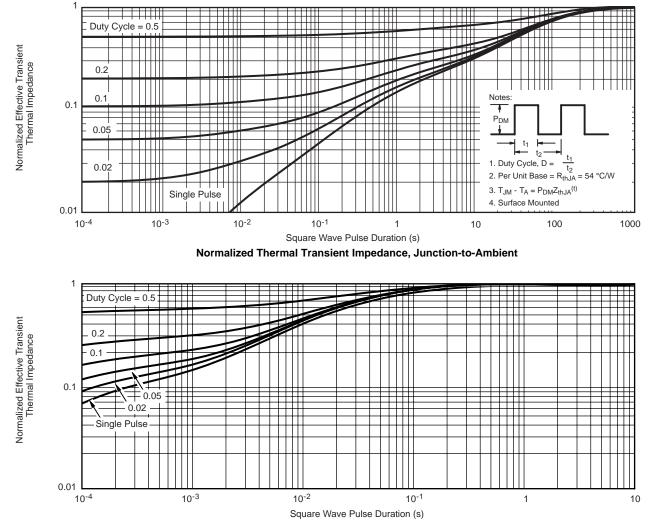








* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

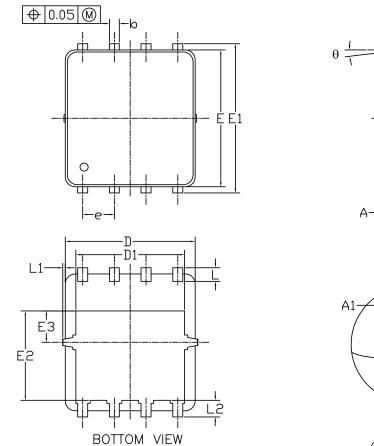


Normalized Thermal Transient Impedance, Junction-to-Case

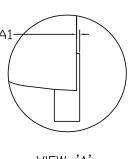
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VIEW 'A'

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DFN5x6_8L_EP1_P PACKAGE OUTLIN



<u>VIEW 'A'</u> (SCALE 5:1)

RECOMMENDED LAND PATTERN .60 -0.55 0.50 -0.77 -0.635 4.12 6.15 -1.60 + $\left|+\right|$ + 0.65 +t -11.27-0.50-

SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
SYMBOLS	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.85	0.95	1.00	0.033	0.037	0.039
Al	0.00		0.05	0.000		0.002
b	0.30	0.40	0.50	0.012	0.016	0.020
с	0.15	0.20	0.25	0.006	0.008	0.010
D	4.80	5.20	5.30	0.201	0.205	0.209
D1	4.25	4.35	4.45	0.167	0.171	0.175
Е	5.45	5.55	5.65	0.215	0.219	0.222
E1	5.95	6.05	6.15	0.234	0.238	0.242
E2	3.525	3.625	3.725	0.139	0.143	0.147
E3	1.175	1.275	1.375	0.046	0.050	0.054
е	1.27 BSC			0.050 BSC		
L	0.45	0.55	0.65	0.018	0.022	0.026
L1	0		0.15	0		0.006
L2	0.68 REF			0.027 REF		
θ	0°		10°	0°		10°

UNIT: mm

NOTE 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH. 2. CONTROLLING DIMENSION IS MILLIMETER.

CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.



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